



# JCS160N08I

## 主要参数 MAIN CHARACTERISTICS

$I_D$	160A
$V_{DSS}$	80V
$R_{dson-max}$ (@ $V_{GS}=10V$ )	5.5m $\Omega$
$Q_g-typ$	133nC

### 用途

- 高功率 DC/DC 转换与功率开关
- 直流电机控制
- 汽车应用
- 不间断电源

### 产品特性

- 低栅极电荷
- 低  $R_{dson}$ (典型值 4.3m $\Omega$ )
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

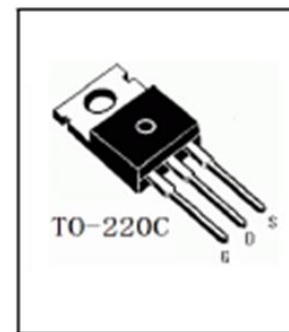
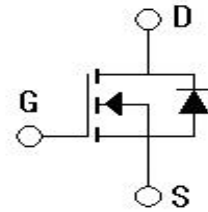
### APPLICATIONS

- High power DC/DC converters and switch mode power supplies
- DC motor control
- Automotive applications
- Uninterruptible power supply

### FEATURES

- Low gate charge
- Low  $R_{dson}$ (typical 4.3m $\Omega$ )
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

## 封装 Package



## 订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
JCS160N08I-C-B	JCS160N08I-C-BR	N/A	N/A	JCS160N08	TO-220C





## 绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
		JCS160N08I(TO-220C)	
最高漏极-源极直流电压 Drain-Source Voltage	V <sub>DSS</sub>	80	V
连续漏极电流 Drain Current -continuous	I <sub>D</sub> T=25°C	160*	A
	I <sub>D</sub> T=100°C	128*	A
最大脉冲漏极电流 (注1) Drain Current - pulse (note 1)	I <sub>DM</sub>	640*	A
最高栅源电压 Gate-Source Voltage	V <sub>GSS</sub>	±20	V
单脉冲雪崩能量 (注2) Single Pulsed Avalanche Energy (note 2)	E <sub>AS</sub>	1200	mJ
雪崩电流 (注1) Avalanche Current (note 1)	I <sub>AR</sub>	70	A
重复雪崩能量 (注1) Repetitive Avalanche Current (note 1)	E <sub>AR</sub>	600	mJ
二极管反向恢复最大电压变化 速率 (注3) Peak Diode Recovery dv/dt (note 3)	dv/dt	18	V/ns
耗散功率 Power Dissipation	P <sub>D</sub> T <sub>C</sub> =25°C -Derate above 25°C	250	W
		1.67	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~+175	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T <sub>L</sub>	300	°C

\*漏极电流由最高结温限制

\*Drain current limited by maximum junction temperature





## 电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
<b>关态特性 Off –Characteristics</b>						
漏—源击穿电压 Drain-Source Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	80	-	-	V
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=80V, V_{GS}=0V,$ $T_C=25^\circ C$	-	-	1	$\mu A$
		$V_{DS}=80V, V_{GS}=0V,$ $T_C=100^\circ C$	-	-	10	$\mu A$
正向栅极体漏电流 Gate-body leakage current, forward	$I_{GSSF}$	$V_{DS}=0V, V_{GS}=20V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	$I_{GSSR}$	$V_{DS}=0V, V_{GS}=-20V$	-	-	-100	nA
<b>通态特性 On-Characteristics</b>						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D=40A$	-	4.3	5.5	m $\Omega$
正向跨导 Forward Transconductance	$g_{fs}$	$V_{DS} = 40V, I_D=20A$ (note 4)	-	30	-	S
<b>动态特性 Dynamic Characteristics</b>						
输入电容 Input capacitance	$C_{iss}$	$V_{DS}=25V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	6600	-	pF
输出电容 Output capacitance	$C_{oss}$		-	585	-	pF
反向传输电容 Reverse transfer capacitance	$C_{rss}$		-	316	-	pF





## 电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{DD}=40V, I_D=50A, R_G=25\Omega$ (note 4, 5)	-	104	-	ns
上升时间 Turn-On rise time	$t_r$		-	186	-	ns
延迟时间 Turn-Off delay time	$t_{d(off)}$		-	343	-	ns
下降时间 Turn-Off Fall time	$t_f$		-	181	-	ns
栅极电荷总量 Total Gate Charge	$Q_g$	$V_{DS}=50V,$ $I_D=50A$ $V_{GS}=10V$ (note 4, 5)	-	133	-	nC
栅-源电荷 Gate-Source charge	$Q_{gs}$		-	36	-	nC
栅-漏电荷 Gate-Drain charge	$Q_{gd}$		-	40	-	nC
漏-源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings						
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current		$I_S$	-	-	160	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current		$I_{SM}$	-	-	640	A
正向压降 Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V,$ $I_S=40A$	-	-	1.2	V
反向恢复时间 Reverse recovery time	$t_{rr}$	$V_{GS}=0V, I_S=40A$ $di_F/dt=100A/\mu s$ (note 4)	-	49	-	ns
反向恢复电荷 Reverse recovery charge	$Q_{rr}$		-	91	-	nC

## 热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大 Max	单 位 Unit
		JCS160N08I	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.60	$^{\circ}C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5	$^{\circ}C/W$

注释:

- 1: 脉冲宽度由最高结温限制
- 2:  $L=0.5mH, I_{AS}=56A, V_{DD}=64V, R_G=25\Omega$ , 起始结温  $T_J=25^{\circ}C$
- 3:  $I_{SD} \leq 160A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$ , 起始结温  $T_J=25^{\circ}C$
- 4: 脉冲测试: 脉冲宽度  $\leq 300\mu s$ , 占空比  $\leq 2\%$
- 5: 基本与工作温度无关

Notes:

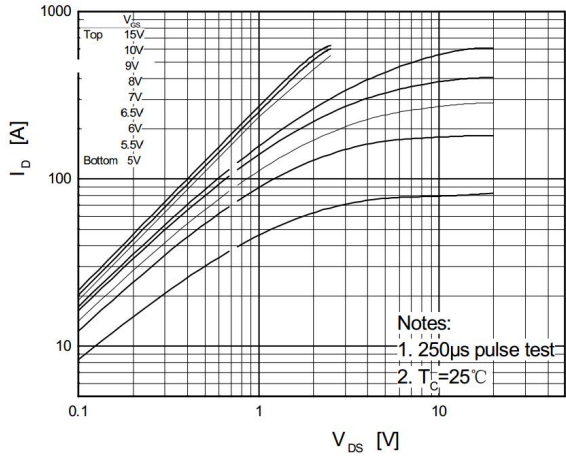
- 1: Pulse width limited by maximum junction temperature
- 2:  $L=0.5mH, I_{AS}=56A, V_{DD}=64V, R_G=25\Omega$ , Starting  $T_J=25^{\circ}C$
- 3:  $I_{SD} \leq 160A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$ , Starting  $T_J=25^{\circ}C$
- 4: Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$
- 5: Essentially independent of operating temperature



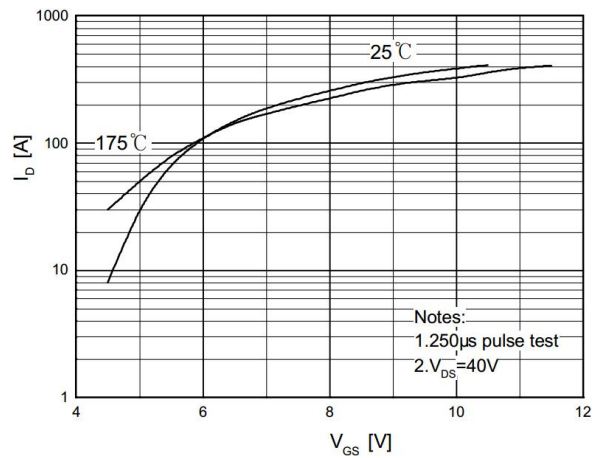


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

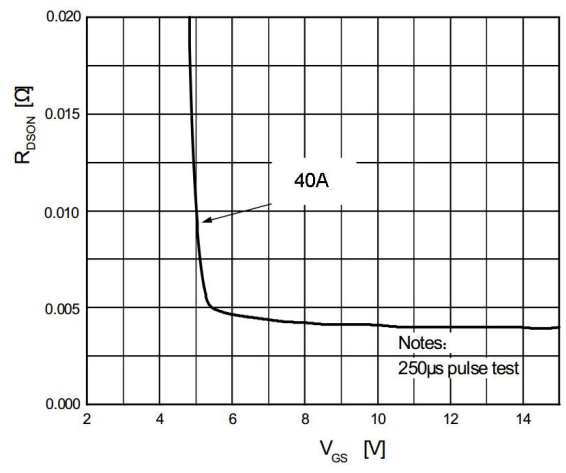
On-Region Characteristics



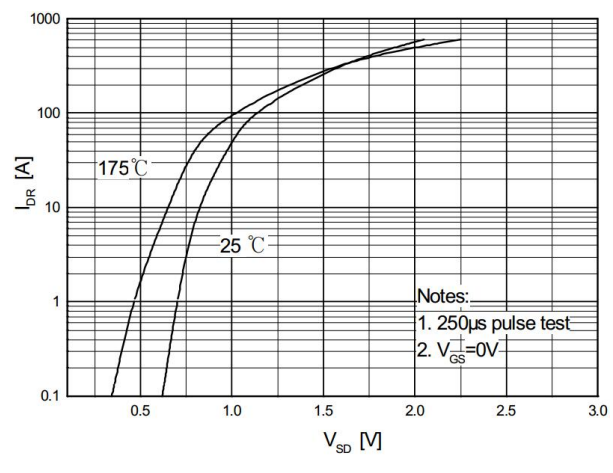
Transfer Characteristics



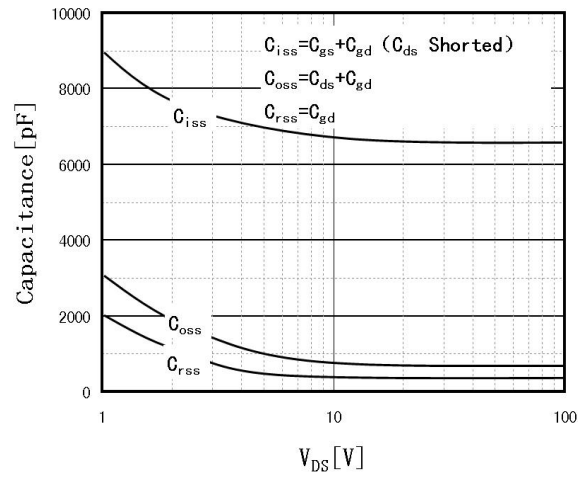
On-Resistance Variation vs. Drain Current and Gate Voltage



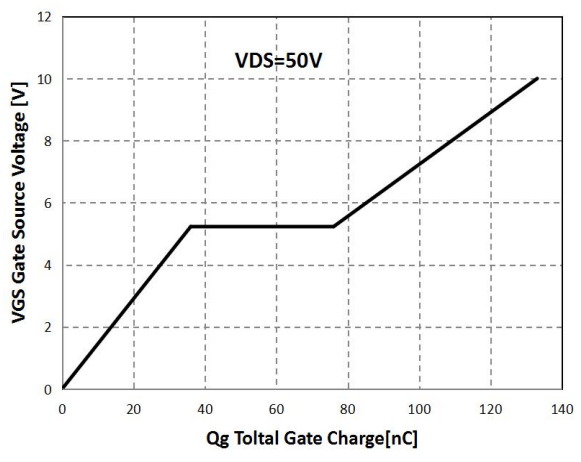
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics



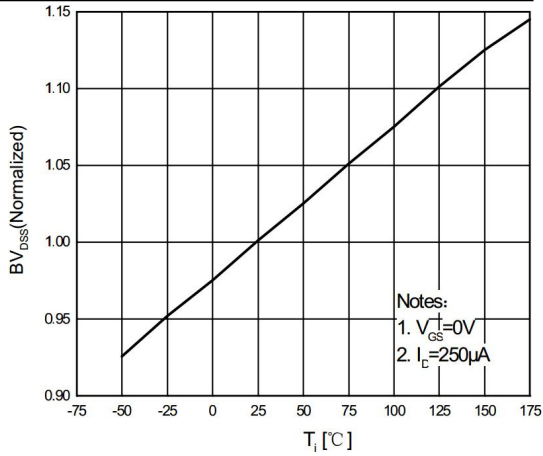
Gate Charge Characteristics



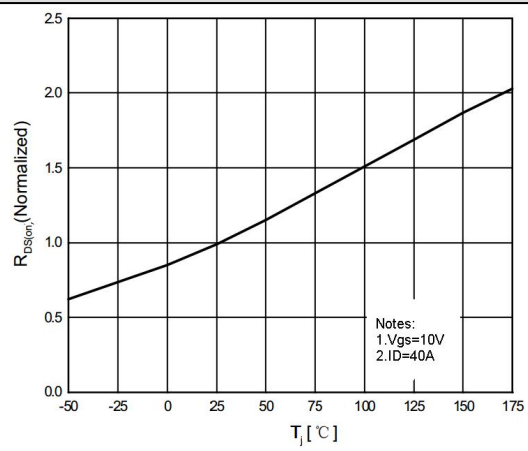


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

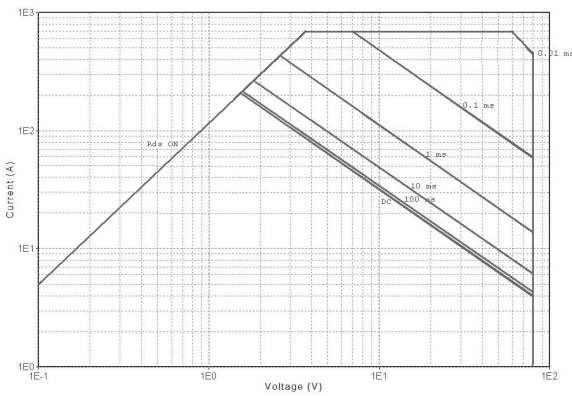
Breakdown Voltage Variation vs. Temperature



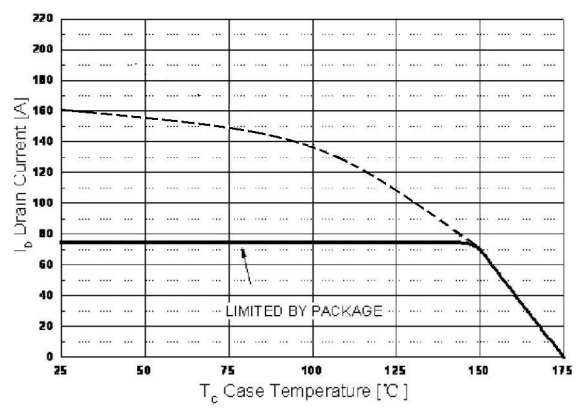
On-Resistance Variation vs. Temperature



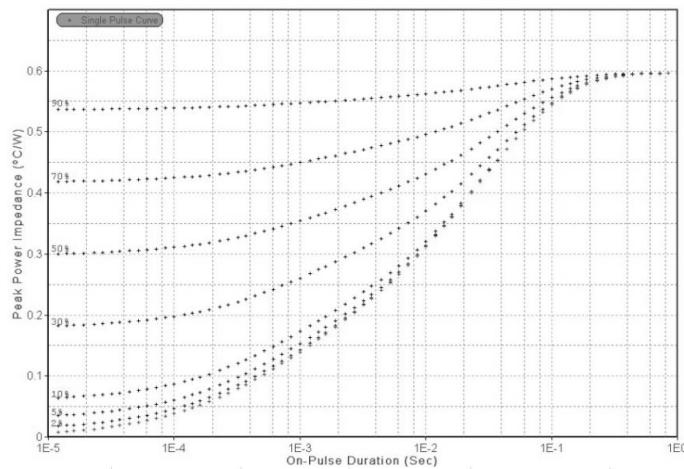
Maximum Safe Operating Area For JCS160N08I(TO-220C)



Maximum Drain Current vs. Case Temperature



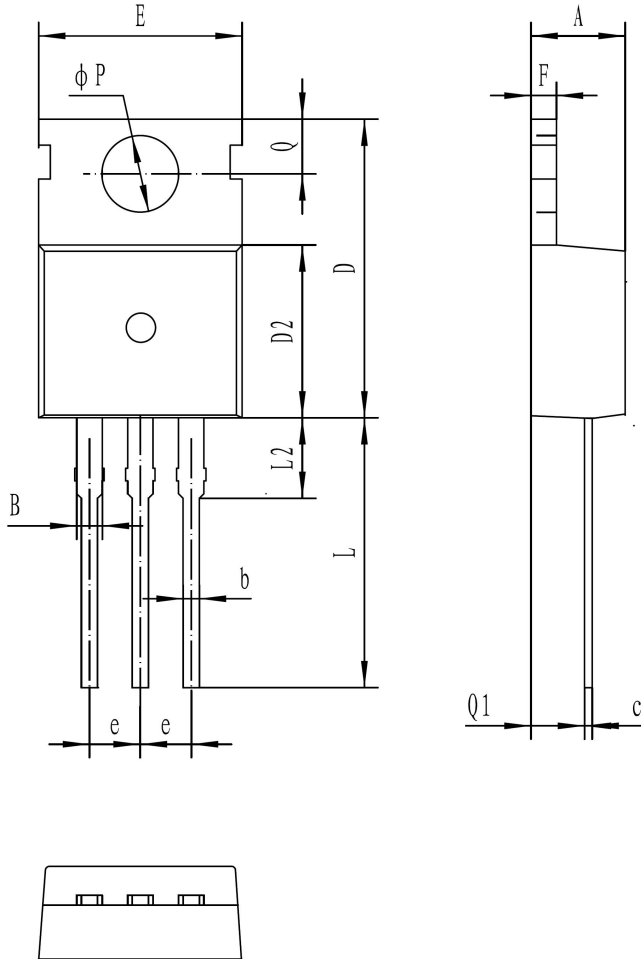
Transient Thermal Response Curve For JCS160N08I(TO-220C)





## TO-220C

单位 Unit: mm



符号 symbol	MIN	MAX
A	4.30	4.70
B	1.10	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80



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